**Features**

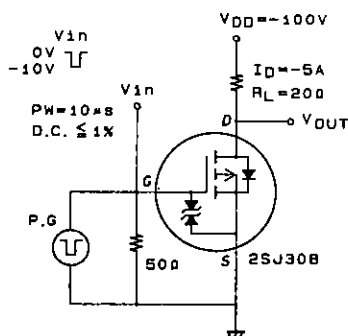
- Low ON resistance.
- Very high-speed switching.
- Low-voltage drive.
- Micaless package facilitating mounting.

Absolute Maximum Ratings at Ta = 25°C

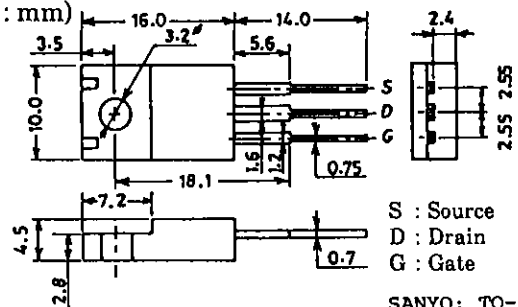
			unit
Drain to Source Voltage	V _{DS}	-250	V
Gate to Source Voltage	V _{GSS}	±30	V
Drain Current(DC)	I _D	-9	A
Drain Current(Pulse)	I _{DP}	PW ≤ 10 μs, duty cycle ≤ 1%	-36 A
Allowable Power Dissipation	P _D	2.0	W
		T _c = 25°C	40 W
Channel Temperature	T _{ch}	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Electrical Characteristics at Ta = 25°C

			min	typ	max	unit
D-S Breakdown Voltage	V _{(BR)DSS}	I _D = -1mA, V _{GS} = 0	-250			V
G-S Breakdown Voltage	V _{(BR)GSS}	I _G = ±100 μA, V _{DS} = 0	±30			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -250V, V _{GS} = 0			-100	μA
Gate to Source Leakage Current	I _{GSS}	V _{GS} = ±25V, V _{DS} = 0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} = -10V, I _D = -1mA	-1.5		-2.5	V
Forward Transfer Admittance	Y _{fs}	V _{DS} = -10V, I _D = -5A	6	10		S
Static Drain to Source on State Resistance	R _{DS(on)}	I _D = -5A, V _{GS} = -10V	0.35	0.48		Ω
Input Capacitance	C _{iss}	V _{DS} = -20V, f = 1MHz		2700		pF
Output Capacitance	C _{oss}	V _{DS} = -20V, f = 1MHz		500		pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} = -20V, f = 1MHz		225		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit.		40		ns
Rise Time	t _r	"		75		ns
Turn-OFF Delay Time	t _{d(off)}	"		320		ns
Fall Time	t _f	"		260		ns
Diode Forward Voltage	V _{SD}	I _S = -9A, V _{GS} = 0	-1.0	-1.5		V

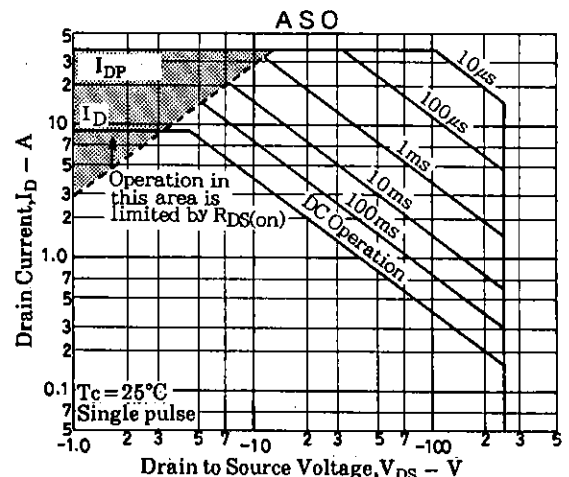
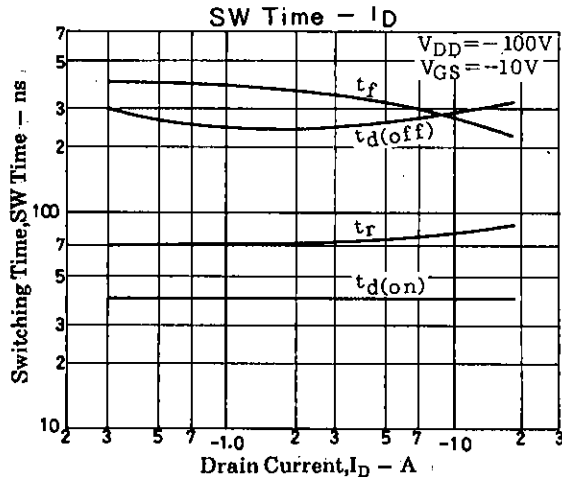
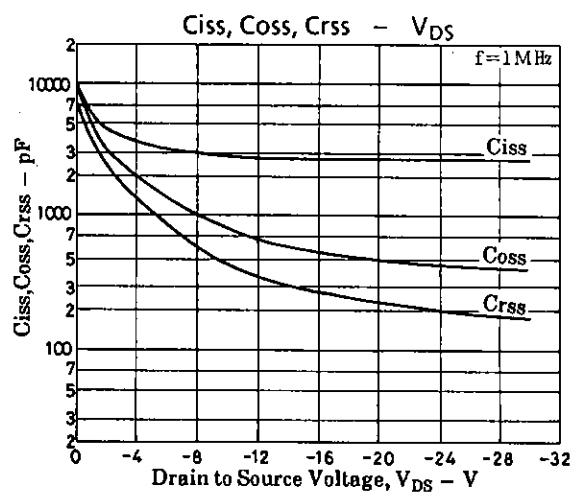
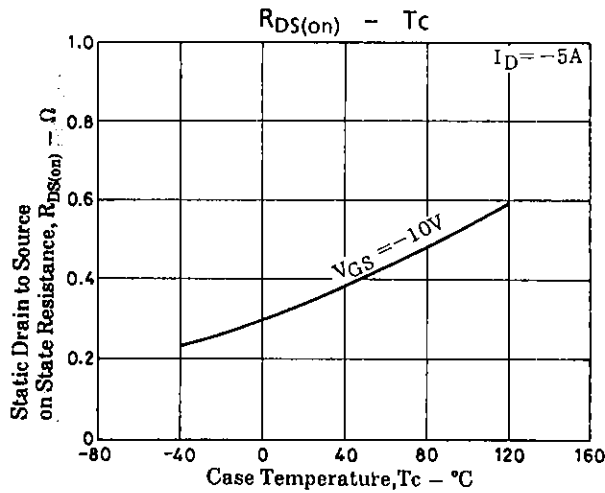
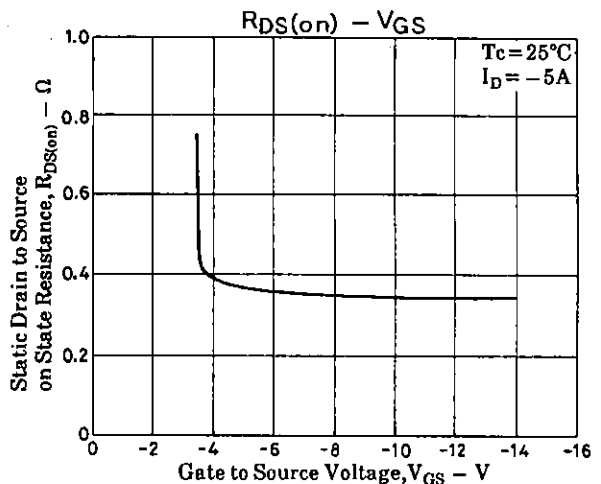
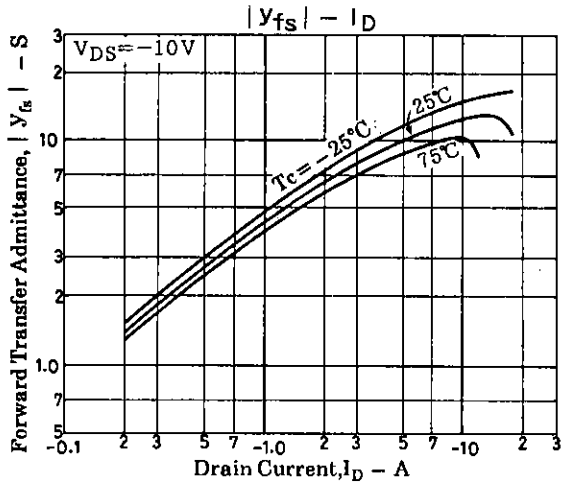
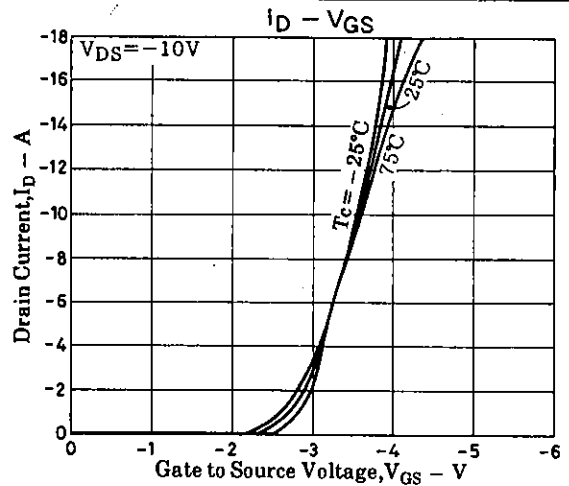
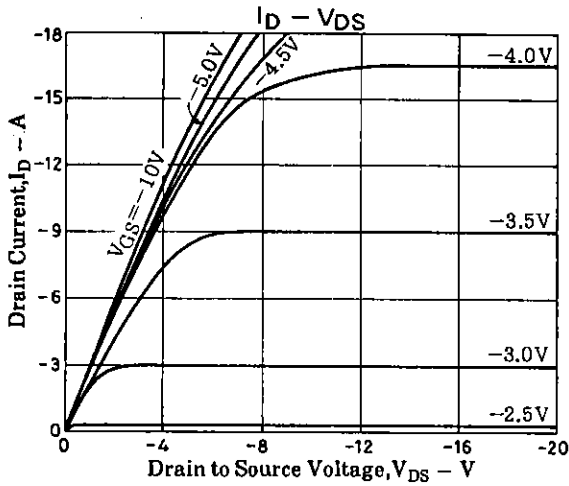
Switching Time Test Circuit**Package Dimensions 2063**

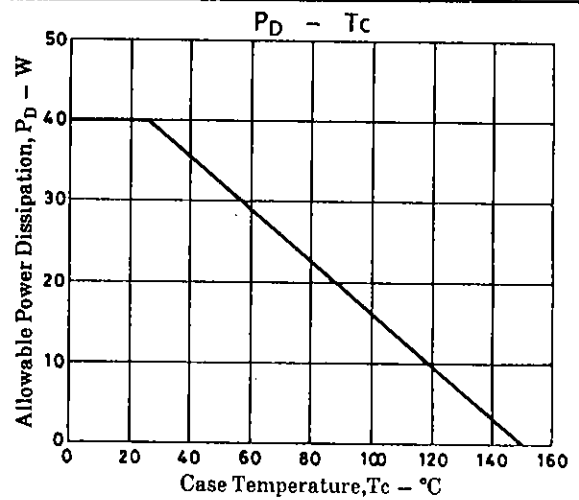
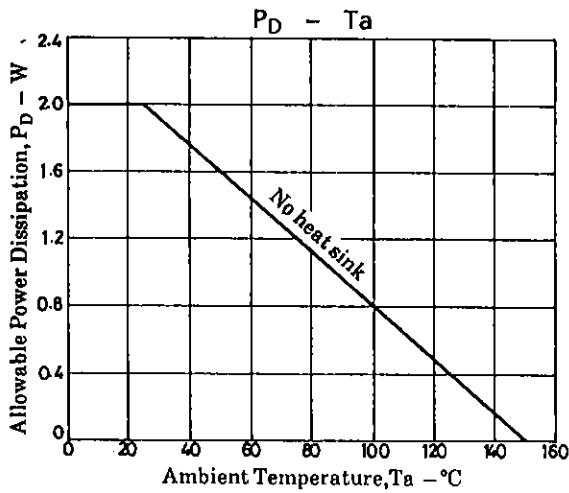
(unit: mm)



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